

# INTERNATIONAL STANDARD

# NORME INTERNATIONALE



**Power losses in voltage sourced converter (VSC) valves for high-voltage direct current (HVDC) systems –  
Part 1: General requirements**

**Pertes de puissance dans les valves à convertisseur de source de tension (VSC) des systèmes en courant continu à haute tension (CCHT) –  
Partie 1: Exigences générales**

[IEC 62751-1:2014](#)

<https://standards.iteh.ai/catalog/standards/iec/017874a9-a976-4fdb-93c0-6422ad7d423f/iec-62751-1-2014>



## THIS PUBLICATION IS COPYRIGHT PROTECTED

Copyright © 2018 IEC, Geneva, Switzerland

All rights reserved. Unless otherwise specified, no part of this publication may be reproduced or utilized in any form or by any means, electronic or mechanical, including photocopying and microfilm, without permission in writing from either IEC or IEC's member National Committee in the country of the requester. If you have any questions about IEC copyright or have an enquiry about obtaining additional rights to this publication, please contact the address below or your local IEC member National Committee for further information.

Droits de reproduction réservés. Sauf indication contraire, aucune partie de cette publication ne peut être reproduite ni utilisée sous quelque forme que ce soit et par aucun procédé, électronique ou mécanique, y compris la photocopie et les microfilms, sans l'accord écrit de l'IEC ou du Comité national de l'IEC du pays du demandeur. Si vous avez des questions sur le copyright de l'IEC ou si vous désirez obtenir des droits supplémentaires sur cette publication, utilisez les coordonnées ci-après ou contactez le Comité national de l'IEC de votre pays de résidence.

IEC Central Office  
3, rue de Varembe  
CH-1211 Geneva 20  
Switzerland

Tel.: +41 22 919 02 11  
[info@iec.ch](mailto:info@iec.ch)  
[www.iec.ch](http://www.iec.ch)

### About the IEC

The International Electrotechnical Commission (IEC) is the leading global organization that prepares and publishes International Standards for all electrical, electronic and related technologies.

### About IEC publications

The technical content of IEC publications is kept under constant review by the IEC. Please make sure that you have the latest edition, a corrigenda or an amendment might have been published.

#### IEC Catalogue - [webstore.iec.ch/catalogue](http://webstore.iec.ch/catalogue)

The stand-alone application for consulting the entire bibliographical information on IEC International Standards, Technical Specifications, Technical Reports and other documents. Available for PC, Mac OS, Android Tablets and iPad.

#### IEC publications search - [webstore.iec.ch/advsearchform](http://webstore.iec.ch/advsearchform)

The advanced search enables to find IEC publications by a variety of criteria (reference number, text, technical committee,...). It also gives information on projects, replaced and withdrawn publications.

#### IEC Just Published - [webstore.iec.ch/justpublished](http://webstore.iec.ch/justpublished)

Stay up to date on all new IEC publications. Just Published details all new publications released. Available online and also once a month by email.

#### Electropedia - [www.electropedia.org](http://www.electropedia.org)

The world's leading online dictionary of electronic and electrical terms containing 21 000 terms and definitions in English and French, with equivalent terms in 16 additional languages. Also known as the International Electrotechnical Vocabulary (IEV) online.

#### IEC Glossary - [std.iec.ch/glossary](http://std.iec.ch/glossary)

67 000 electrotechnical terminology entries in English and French extracted from the Terms and Definitions clause of IEC publications issued since 2002. Some entries have been collected from earlier publications of IEC TC 37, 77, 86 and CISPR.

#### IEC Customer Service Centre - [webstore.iec.ch/csc](http://webstore.iec.ch/csc)

If you wish to give us your feedback on this publication or need further assistance, please contact the Customer Service Centre: [sales@iec.ch](mailto:sales@iec.ch).

### A propos de l'IEC

La Commission Electrotechnique Internationale (IEC) est la première organisation mondiale qui élabore et publie des Normes internationales pour tout ce qui a trait à l'électricité, à l'électronique et aux technologies apparentées.

### A propos des publications IEC

Le contenu technique des publications IEC est constamment revu. Veuillez vous assurer que vous possédez l'édition la plus récente, un corrigendum ou amendement peut avoir été publié.

#### Catalogue IEC - [webstore.iec.ch/catalogue](http://webstore.iec.ch/catalogue)

Application autonome pour consulter tous les renseignements bibliographiques sur les Normes internationales, Spécifications techniques, Rapports techniques et autres documents de l'IEC. Disponible pour PC, Mac OS, tablettes Android et iPad.

#### Recherche de publications IEC - [webstore.iec.ch/advsearchform](http://webstore.iec.ch/advsearchform)

La recherche avancée permet de trouver des publications IEC en utilisant différents critères (numéro de référence, texte, comité d'études,...). Elle donne aussi des informations sur les projets et les publications remplacées ou retirées.

#### IEC Just Published - [webstore.iec.ch/justpublished](http://webstore.iec.ch/justpublished)

Restez informé sur les nouvelles publications IEC. Just Published détaille les nouvelles publications parues. Disponible en ligne et aussi une fois par mois par email.

#### Electropedia - [www.electropedia.org](http://www.electropedia.org)

Le premier dictionnaire en ligne de termes électroniques et électriques. Il contient 21 000 termes et définitions en anglais et en français, ainsi que les termes équivalents dans 16 langues additionnelles. Egalement appelé Vocabulaire Electrotechnique International (IEV) en ligne.

#### Glossaire IEC - [std.iec.ch/glossary](http://std.iec.ch/glossary)

67 000 entrées terminologiques électrotechniques, en anglais et en français, extraites des articles Termes et Définitions des publications IEC parues depuis 2002. Plus certaines entrées antérieures extraites des publications des CE 37, 77, 86 et CISPR de l'IEC.

#### Service Clients - [webstore.iec.ch/csc](http://webstore.iec.ch/csc)

Si vous désirez nous donner des commentaires sur cette publication ou si vous avez des questions contactez-nous: [sales@iec.ch](mailto:sales@iec.ch).

# INTERNATIONAL STANDARD

# NORME INTERNATIONALE



**Power losses in voltage sourced converter (VSC) valves for high-voltage direct current (HVDC) systems –  
Part 1: General requirements**

**Pertes de puissance dans les valves à convertisseur de source de tension (VSC) des systèmes en courant continu à haute tension (CCHT) –  
Partie 1: Exigences générales**

<https://standards.iteh.ai/catalog/standards/iec/017874a9-a976-4fdb-93c0-6422ad7d423f/iec-62751-1-2014>

INTERNATIONAL  
ELECTROTECHNICAL  
COMMISSION

COMMISSION  
ELECTROTECHNIQUE  
INTERNATIONALE

ICS 29.200; 29.240.99

ISBN 978-2-8322-5623-7

**Warning! Make sure that you obtained this publication from an authorized distributor.  
Attention! Veuillez vous assurer que vous avez obtenu cette publication via un distributeur agréé.**



## REDLINE VERSION

## VERSION REDLINE



**Power losses in voltage sourced converter (VSC) valves for high-voltage direct current (HVDC) systems –  
Part 1: General requirements**

**Pertes de puissance dans les valves à convertisseur de source de tension (VSC)  
des systèmes en courant continu à haute tension (CCHT) –  
Partie 1: Exigences générales**

[IEC 62751-1:2014](#)

<https://standards.iteh.ai/catalog/standards/iec/017874a9-a976-4fdb-93c0-6422ad7d423f/iec-62751-1-2014>

## CONTENTS

FOREWORD.....	4
1 Scope.....	6
2 Normative references .....	6
3 Terms and definitions .....	6
3.1 Converter types .....	7
3.2 Semiconductor devices .....	7
3.3 Converter operating states .....	8
3.4 Device characteristics .....	8
3.5 Other definitions .....	9
4 General conditions.....	10
4.1 General.....	10
4.2 Causes of power losses .....	11
4.3 Categories of valve losses .....	11
4.4 Operating conditions .....	12
4.4.1 General .....	12
4.4.2 Reference ambient conditions.....	12
4.4.3 Reference a.c. system conditions .....	12
4.4.4 Converter operating states.....	12
4.4.5 Treatment of redundancy.....	13
4.5 Use of real measured data .....	13
4.5.1 General .....	13
4.5.2 Routine testing .....	13
4.5.3 Characterisation testing.....	13
5 Conduction losses .....	14
5.1 General.....	14
5.2 IGBT conduction losses .....	16
5.3 Diode conduction losses .....	16
5.4 Other conduction losses.....	17
6 D.C. voltage-dependent losses .....	17
7 Losses in d.c. capacitors .....	18
8 Switching losses.....	18
8.1 General.....	18
8.2 IGBT switching losses.....	19
8.3 Diode switching losses.....	20
9 Other losses .....	21
9.1 Snubber circuit losses.....	21
9.2 Valve electronics power consumption.....	21
10 Total valve losses per converter substation .....	22
Annex A (informative) Determination of power losses in other HVDC substation equipment.....	25
A.1 General.....	25
A.2 Guidance for calculating losses in each equipment .....	25
A.2.1 Circuit breaker .....	25
A.2.2 Pre-insertion resistor .....	25
A.2.3 Line side harmonic filter.....	26

A.2.4	Line side high frequency filter .....	26
A.2.5	Interface transformer .....	27
A.2.6	Converter side harmonic filter .....	27
A.2.7	Converter side high frequency filter .....	27
A.2.8	Phase reactor .....	27
A.2.9	VSC unit .....	27
A.2.10	VSC d.c. capacitor .....	27
A.2.11	D.C. harmonic filter .....	27
A.2.12	Dynamic braking system .....	28
A.2.13	Neutral point grounding branch .....	28
A.2.14	D.C. reactor .....	28
<del>A.2.15</del>	<del>Common mode blocking reactor .....</del>	<del>28</del>
A.2.16	D.C. side high frequency filter .....	28
A.2.17	D.C. cable or overhead transmission line .....	29
A.3	Auxiliaries and station service losses .....	29
Bibliography .....		30
Figure 1 – On-state voltage of an IGBT or diode .....		14
Figure 2 – Piecewise-linear representation of IGBT or diode on-state voltage .....		15
Figure 3 – IGBT switching energy as a function of collector current .....		19
Figure 4 – Diode recovery energy as a function of current .....		20
Figure A.1 – Major components that may be found in a VSC substation .....		26
Table 1 – Matrix indicating the relationship of data needed for calculation of losses and the type of valve losses (1 of 2) .....		23

## INTERNATIONAL ELECTROTECHNICAL COMMISSION

**POWER LOSSES IN VOLTAGE SOURCED CONVERTER (VSC)  
VALVES FOR HIGH-VOLTAGE DIRECT CURRENT (HVDC) SYSTEMS –****Part 1: General requirements**

## FOREWORD

- 1) The International Electrotechnical Commission (IEC) is a worldwide organization for standardization comprising all national electrotechnical committees (IEC National Committees). The object of IEC is to promote international co-operation on all questions concerning standardization in the electrical and electronic fields. To this end and in addition to other activities, IEC publishes International Standards, Technical Specifications, Technical Reports, Publicly Available Specifications (PAS) and Guides (hereafter referred to as “IEC Publication(s)”). Their preparation is entrusted to technical committees; any IEC National Committee interested in the subject dealt with may participate in this preparatory work. International, governmental and non-governmental organizations liaising with the IEC also participate in this preparation. IEC collaborates closely with the International Organization for Standardization (ISO) in accordance with conditions determined by agreement between the two organizations.
- 2) The formal decisions or agreements of IEC on technical matters express, as nearly as possible, an international consensus of opinion on the relevant subjects since each technical committee has representation from all interested IEC National Committees.
- 3) IEC Publications have the form of recommendations for international use and are accepted by IEC National Committees in that sense. While all reasonable efforts are made to ensure that the technical content of IEC Publications is accurate, IEC cannot be held responsible for the way in which they are used or for any misinterpretation by any end user.
- 4) In order to promote international uniformity, IEC National Committees undertake to apply IEC Publications transparently to the maximum extent possible in their national and regional publications. Any divergence between any IEC Publication and the corresponding national or regional publication shall be clearly indicated in the latter.
- 5) IEC itself does not provide any attestation of conformity. Independent certification bodies provide conformity assessment services and, in some areas, access to IEC marks of conformity. IEC is not responsible for any services carried out by independent certification bodies.
- 6) All users should ensure that they have the latest edition of this publication.
- 7) No liability shall attach to IEC or its directors, employees, servants or agents including individual experts and members of its technical committees and IEC National Committees for any personal injury, property damage or other damage of any nature whatsoever, whether direct or indirect, or for costs (including legal fees) and expenses arising out of the publication, use of, or reliance upon, this IEC Publication or any other IEC Publications.
- 8) Attention is drawn to the Normative references cited in this publication. Use of the referenced publications is indispensable for the correct application of this publication.
- 9) Attention is drawn to the possibility that some of the elements of this IEC Publication may be the subject of patent rights. IEC shall not be held responsible for identifying any or all such patent rights.

**This consolidated version of the official IEC Standard and its amendment has been prepared for user convenience.**

**IEC 62751-1 edition 1.1 contains the first edition (2014-08) [documents 22F/302/CDV and 22F/321A/RVC] and its amendment 1 (2018-04) [documents 22F/439A/CDV and 22F/458A/RVC].**

**In this Redline version, a vertical line in the margin shows where the technical content is modified by amendment 1. Additions are in green text, deletions are in strikethrough red text. A separate Final version with all changes accepted is available in this publication.**



International Standard IEC 62751-1 has been prepared by subcommittee 22F: Power electronics for electrical transmission and distribution systems, of IEC technical committee 22: Power electronic systems and equipment.

This publication has been drafted in accordance with the ISO/IEC Directives, Part 2.

A list of all parts in the IEC 62751series, published under the general title *Power losses in voltage sourced converter (VSC) valves for high-voltage direct current (HVDC) systems*, can be found on the IEC website.

The committee has decided that the contents of the base publication and its amendment will remain unchanged until the stability date indicated on the IEC web site under "<http://webstore.iec.ch>" in the data related to the specific publication. At this date, the publication will be

- reconfirmed,
- withdrawn,
- replaced by a revised edition, or
- amended.

**IMPORTANT – The 'colour inside' logo on the cover page of this publication indicates that it contains colours which are considered to be useful for the correct understanding of its contents. Users should therefore print this document using a colour printer.**

(<https://standards.iteh.ai>)  
Document Preview

[IEC 62751-1:2014](#)

<https://standards.iteh.ai/catalog/standards/iec/017874a9-a976-4fdb-93c0-6422ad7d423f/iec-62751-1-2014>

# POWER LOSSES IN VOLTAGE SOURCED CONVERTER (VSC) VALVES FOR HIGH-VOLTAGE DIRECT CURRENT (HVDC) SYSTEMS –

## Part 1: General requirements

### 1 Scope

This part of IEC 62751 sets out the general principles for calculating the power losses in the converter valves of a voltage sourced converter (VSC) for high-voltage direct current (HVDC) applications, independent of the converter topology. Clauses 6 and 8 and subclauses 9.1, 9.2 and A.2.12 of the standard can also be used for calculating the power losses in the dynamic braking valves (where used) and as guidance for calculating the power losses of the valves for a STATCOM installation.

Power losses in other items of equipment in the HVDC substation, apart from the converter valves, are excluded from the scope of this standard. Power losses in most equipment in a VSC substation can be calculated using similar procedures to those prescribed for HVDC systems with line-commutated converters (LCC) in IEC 61803. Annex A presents the main differences between LCC and VSC HVDC substations in so far as they influence the method for determining power losses of other equipment.

This standard does not apply to converter valves for line-commutated converter HVDC systems.

### 2 Normative references

The following documents, in whole or in part, are normatively referenced in this document and are indispensable for its application. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

IEC 60633, *Terminology for high-voltage direct current (HVDC) transmission*

IEC 60747-2, *Semiconductor devices – Discrete devices and integrated circuits – Part 2: Rectifier diodes*

IEC 60747-9:2007, *Semiconductor devices – Discrete devices – Part 9: Insulated-gate bipolar transistors (IGBTs)*

IEC 62747:2014, *Terminology for voltage-sourced converters (VSC) for high-voltage direct current (HVDC) systems*

ISO/IEC Guide 98-3, *Uncertainty of measurement – Part 3: Guide to the expression of uncertainty in measurement (GUM:1995)*

### 3 Terms and definitions

For the purposes of this document, the terms and definitions given in IEC 60633, IEC 62747, IEC 60747-2, IEC 60747-9 as well as the following apply.

NOTE 1 Related terms and definitions can also be found in IEC TR 62543, IEC 62751-2 and in the other relevant parts of the IEC 60747 series.

NOTE 2 Throughout this standard, the term “insulated gate bipolar transistor (IGBT)” is used to indicate a turn-off semiconductor device; however, the standard is equally applicable to other types of turn-off semiconductor devices such as the GTO, IGCT, ETO, IEGT, etc.

### 3.1 Converter types

#### 3.1.1

##### **2-level converter**

converter in which the voltage between the a.c. terminals of the VSC unit and VSC unit midpoint is switched between two discrete d.c. voltage levels

Note 1 to entry: VSC unit midpoint is defined in 3.5.9.

#### 3.1.2

##### **multi-level converter**

converter in which the voltage between the a.c. terminals of the VSC unit and VSC unit midpoint is switched between more than three discrete d.c. voltage levels

Note 1 to entry: VSC unit midpoint is defined in 3.5.9.

#### 3.1.3

##### **modular multi-level converter**

##### **MMC**

multi-level converter in which each VSC valve consists of a number of MMC building blocks connected in series

Note 1 to entry: MMC building block is defined in 3.5.4.

Note 2 to entry: This note applies to the French language only.

#### 3.1.4

##### **cascaded two-level converter**

##### **CTL**

modular multi-level converter in which each switch position consists of more than one IGBT-diode pair connected in series

Note 1 to entry: IGBT-diode pair is defined in 3.2.4.

Note 2 to entry: This note applies to the French language only.

### 3.2 Semiconductor devices

#### 3.2.1

##### **turn-off semiconductor device**

controllable semiconductor device which may be turned on and off by a control signal, for example an IGBT

#### 3.2.2

##### **insulated gate bipolar transistor**

##### **IGBT**

turn-off semiconductor device with three terminals: a gate terminal (G) and two load terminals emitter (E) and collector (C)

Note 1 to entry: By applying appropriate gate to emitter voltages, current in one direction can be controlled, i.e. turned on and turned off.

Note 2 to entry: This note applies to the French language only.

#### 3.2.3

##### **free-wheeling diode**

##### **FWD**

power semiconductor device with diode characteristic

Note 1 to entry: A FWD has two terminals: an anode (A) and a cathode (K). The current through FWDs is in opposite direction to the IGBT current. FWDs are characterized by the capability to cope with high rates of decrease of current caused by the switching behaviour of the IGBT.

Note 2 to entry: This note applies to the French language only.

### 3.2.4

#### IGBT-diode pair

arrangement of IGBT and FWD connected in inverse parallel

Note 1 to entry: An IGBT-diode pair is usually in one common package; however, it can include individual IGBTs and/or diodes packages connected in parallel.

## 3.3 Converter operating states

### 3.3.1

#### no-load operating state

condition in which the VSC substation is energized but the IGBTs are blocked and all substation service loads and auxiliary equipment are connected

### 3.3.2

#### idling operating state

condition in which the VSC substation is energized and the IGBTs are de-blocked but with no active or reactive power output at the point of common connection to the a.c. network

Note 1 to entry: The “idling operating” and “no-load” conditions are similar but from the no-load state several seconds may be needed before power can be transmitted, while from the idling operating state, power transmission may be commenced almost immediately (less than 3 power frequency cycles).

Note 2 to entry: In the idling operating state, the converter is capable of actively controlling the d.c. voltage, in contrast to the no-load state where the behaviour of the converter is essentially “passive”.

Note 3 to entry: Losses will generally be slightly lower in the no-load state than in the idling operating state, therefore this operating mode is preferred where the arrangement of the VSC system permits it.

### 3.3.3

#### operating state

condition in which the VSC substation is energized and the converters are de-blocked

Note 1 to entry: Unlike line-commutated converter, VSC can operate with zero active/reactive power output.

### 3.3.4

#### no-load power losses

power losses in the VSC valve in the no-load state

Note 1 to entry: In some converter designs, it may be necessary to make occasional switching operations for the purposes of balancing voltages between different parts of the converter. In such converters, the calculation of no-load losses shall take into account the switching frequency of such an operating mode.

### 3.3.5

#### idling operating losses

losses in the VSC valve in the idling operating state

### 3.3.6

#### operating losses

losses in the VSC valve in the operating state

## 3.4 Device characteristics

### 3.4.1

#### IGBT collector-emitter saturation voltage

$V_{CE(sat)}$

collector-emitter voltage under conditions of gate-emitter voltage at which the collector current is essentially independent of the gate-emitter voltage

### 3.4.2

#### **IGBT turn-on energy**

$E_{on}$

energy dissipated inside the IGBT during the turn-on of a single collector current pulse

### 3.4.3

#### **IGBT turn-off energy**

$E_{off}$

energy dissipated inside the IGBT during the turn-off procedure of a single collector current pulse

### 3.4.4

#### **diode forward voltage**

$V_F$

voltage across the terminals of a diode which results from the flow of current in the forward direction

### 3.4.5

#### **diode reverse recovery energy**

$E_{rec}$

energy dissipated inside the diode during the turn-off procedure

## 3.5 Other definitions

### 3.5.1

#### **VSC valve level**

smallest indivisible functional unit of VSC valve

Note 1 to entry: For any VSC valve in which IGBTs are connected in series and operated simultaneously, one VSC valve level is one IGBT-diode pair including its auxiliaries. For MMC type valve, one valve level is one submodule together with its auxiliaries.

### 3.5.2

#### **redundant levels**

maximum number of series connected VSC valve levels or diode valve levels in a valve that may be short-circuited externally or internally during service without affecting the safe operation of the valve as demonstrated by type tests, and which if and when exceeded, would require shutdown of the valve to replace the failed levels or acceptance of increased risk of failures

Note 1 to entry: In valve designs such as the cascaded two level converter, which contain two or more conduction paths within each cell and have series-connected VSC valve levels in each path, redundant levels shall be counted only in one conduction path in each cell

### 3.5.3

#### **valve electronics**

electronic circuits at valve potential(s) which perform control and protection functions for one or more valve levels

### 3.5.4

#### **MMC building block**

self-contained, two-terminal controllable voltage source together with d.c. capacitor(s) and immediate auxiliaries, forming part of a MMC

### 3.5.5

#### **switch position**

semiconductor function which behaves as a single, indivisible switch

Note 1 to entry: A switch position may consist of a single IGBT-diode pair or, in the case of the cascaded two level converter, a series connection of multiple IGBT-diode pairs.

**3.5.6****submodule**

MMC building block where each switch position consists of only one IGBT-diode pair cell

**3.5.7****cell**

MMC building block where each switch position consists of more than one IGBT-diode pair connected in series

**3.5.8****VSC unit**

three VSC phase units, together with VSC unit control equipment, essential protective and switching devices, d.c. storage capacitors, phase reactors and auxiliaries, if any, used for conversion

**3.5.9****VSC unit midpoint**

point in a VSC unit whose electrical potential is equal to the average of the potentials of the positive and negative d.c. terminals of the VSC unit

Note 1 to entry: In some applications the VSC unit midpoint may exist only as a virtual point, not corresponding to a physical node in the circuit.

**4 General conditions****4.1 General**

Suppliers need to know in detail how and where losses are generated, since this affects component and equipment ratings. Purchasers are interested in a verifiable loss figure which allows equitable bid comparison and in a procedure after delivery which can objectively verify the guaranteed performance requirements of the supplier.

The overall uncertainty of the value of losses is an important parameter for a converter and for a converter station since the value of losses is used to compare investment cost to capitalized cost over the life-time of the converter station. To ensure that estimates are undisputed, adherence to the provisions of this standard and the provisions of ISO/IEC Guide 98-3 is indispensable. All measurements shall furthermore be traceable to national and/or international standards of measurement.

As a general principle, it would be desirable to determine the efficiency of an HVDC converter station by a direct measurement of its energy losses. However, attempts to determine the station losses by subtracting the measured output power from the measured input power should recognize that such measurements have an inherent inaccuracy, especially if performed at high voltage. The losses of an HVDC converter station at full load are generally of the order 1 % of the transmitted power. Therefore, the loss measured as a small difference between two large quantities is not likely to be a sufficiently accurate indication of the actual losses.

In some special circumstances it may be possible, for example, to arrange a temporary test connection in which two converters are operated from the same a.c. source and also connected together via their d.c. terminals. In this connection, the power drawn from the a.c. source equals the losses in the circuit. However, the a.c. source also provides var support and commutating voltage to the two converters. Once again, there are practical measurement difficulties. In order to avoid the problems described above, this standard standardizes a method of calculating the HVDC converter station losses by summing the losses calculated for each item of equipment. The standardized calculation method will help the purchaser to meaningfully compare the competing bids. It will also allow an easy generation of performance curves for the wide range of operating conditions in which the performance has to be known. In the absence of an inexpensive experimental method which could be employed